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SN74AVCH8T245

SCES565H-APRIL 2004-REVISED MARCH 2016

SN74AVCH8T245 8-Bit Dual-Supply Bus Transceiver With Configurable Level-Shifting, Voltage Translation, and 3-State Outputs

1 Features

- Control Inputs (DIR and $\overline{\text{OE}})$ V_{IH} and V_{IL} Levels Are Referenced to V_{CCA} Voltage
- Bus Hold on Data Inputs Eliminates the Need for External Pullup or Pulldown Resistors
- V_{CC} Isolation Feature
- Fully Configurable Dual-Rail Design
- I/Os Are 4.6-V Tolerant
- Ioff Supports Partial-Power-Down Mode Operation
- Max Data Rates:
 - 320 Mbps (V_{CCA} \geq 1.8 V and V_{CCB} \geq 1.8 V)
 - 170 Mbps ($V_{CCA} \le 1.8$ V or $V_{CCB} \le 1.8$ V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 8000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

2 Applications

- Personal Electronics
- Industrial
- Enterprise
- Telecommunications

3 Description

Tools &

Software

The SN74AVCH8T245 is an 8-bit noninverting bus transceiver that uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} , which accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB} , which also accepts any supply voltage from 1.2 V to 3.6 V. This allows for universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

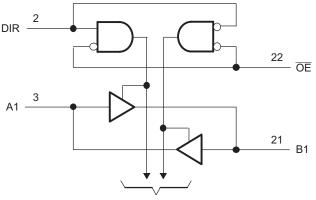
The SN74AVCH8T245 is designed for asynchronous communication between data buses. The device transmits data from either the A bus to the B bus, or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the outputs so the buses are effectively isolated.

Device	Inform	ation ⁽¹⁾
DCVICC		auvi

PACKAGE	BODY SIZE (NOM)			
TVSOP (24)	5.00 mm × 4.40 mm			
TSSOP (24)	7.80 mm × 4.40 mm			
VQFN (24)	5.50 mm × 3.50 mm			
	PACKAGE TVSOP (24) TSSOP (24)			

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram (Positive Logic)



To Seven Other Channels

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (March 2007) to Revision H

P	a	n	ρ
	a	У	C

•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation	
	section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and	
	Mechanical, Packaging, and Orderable Information section.	1
•	Deleted the Ordering Information table. See the POA at the end of the data sheet.	1

2



5 Description (continued)

The SN74AVCH8T245 is designed so that the control pins (DIR and \overline{OE}) are referenced to V_{CCA}.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device.

The V_{CC} isolation feature ensures that if either V_{CCA} or V_{CCB} is at GND, then the outputs are in the high-impedance state. The bus-hold circuitry on the powered-up side always stays active.

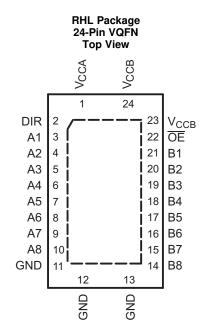
The SN74AVCH8T245 solution is compatible with a single-supply system and can be replaced later with a '245 function, with minimal printed circuit board redesign.

To ensure the high-impedance state during power up or power down, \overline{OE} shall be tied to V_{CCA} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



6 Pin Configuration and Functions

DGV or PW Package 24-Pin TVSOP or TSSOP Top View					
V _{CCA} [DIR [A1 [A2 [A3] A4 [A5] A6 [A7] GND [GND [1 2 3 4 5 6 7 8 9 10 11 12	υ	24 23 22 21 20 19 18 17 16 15 14	V _{CCB} V _{CCB} OE B1 B2 B3 B4 B5 B6 B7 B8	
l					



Pin Functions

	PIN	1/0	DECODIDION			
NAME	NO.	I/O	DESCRIPTION			
A1	3	I/O	Input/output A1. Referenced to V _{CCA} .			
A2	4	I/O	Input/output A2. Referenced to V _{CCA} .			
A3	5	I/O	Input/output A3. Referenced to V _{CCA} .			
A4	6	I/O	Input/output A4. Referenced to V _{CCA} .			
A5	7	I/O	Input/output A5. Referenced to V _{CCA} .			
A6	8	I/O	Input/output A6. Referenced to V _{CCA} .			
A7	9	I/O	Input/output A7. Referenced to V _{CCA} .			
A8	10	I/O	Input/output A8. Referenced to V _{CCA} .			
B1	21	I/O	Input/output B1. Referenced to V _{CCB} .			
B2	20	I/O	Input/output B2. Referenced to V _{CCB} .			
B3	19	I/O	Input/output B3. Referenced to V _{CCB} .			
B4	18	I/O	Input/output B4. Referenced to V _{CCB} .			
B5	17	I/O	Input/output B5. Referenced to V _{CCB} .			
B6	16	I/O	Input/output B6. Referenced to V _{CCB} .			
B7	15	I/O	Input/output B7. Referenced to V _{CCB} .			
B8	14	I/O	Input/output B8. Referenced to V _{CCB} .			
DIR	2	I	Direction-control signal. Referenced to V _{CCA} .			
GND	11, 12, 13	_	Ground			
ŌĒ	22	I	3-state output-mode enables. Pull $\overline{\text{OE}}$ high to place all outputs in 3-state mode. Referenced to V _{CCA} .			
V _{CCA}	1	_	A-port supply voltage. 1.2 V \leq V _{CCA} \leq 3.6 V			
V _{CCB}	23, 24	_	B-port supply voltage. 1.2 V \leq V _{CCA} \leq 3.6 V			

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Specifications 7

Absolute Maximum Ratings 7.1

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage		-0.5	4.6	V
		I/O ports (A port)	-0.5	4.6	
VI	Input voltage ⁽²⁾	I/O ports (B port)	-0.5	4.6	V
		Control inputs	-0.5	4.6	
Vo	Voltage applied to any output in the high-impedance or power-off state ⁽²⁾	A port	-0.5	4.6	V
		B port	-0.5	4.6	
V	Voltage applied to any output in the high or low state $^{(2)(3)}$	A port	-0.5	V _{CCA} + 0.5	V
Vo		B port	-0.5	$V_{CCB} + 0.5$	
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V_{CCA} , V_{CCB} , or GND			±100	mA
TJ	Junction temperature		-40	150	°C
T _{stg}	Storage temperature		-65	150	°C

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings (1) only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed. The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed. (2)

(3)

7.2 ESD Ratings

			VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±8000		
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V	
		Machine model (MM)	±200	

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. (1)

JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. (2)

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7.3 Recommended Operating Conditions

See	(1)(2)
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				MIN	МАХ	UNIT
V _{CCA}	Supply voltage			1.2	3.6	V
V _{CCB}	Supply voltage			1.2	3.6	V
			V _{CCI} = 1.2 V to 1.95 V	$V_{CCI} \times 0.65$		
V _{IH}	High-level input voltage ⁽¹⁾	Data inputs	$V_{CCI} = 1.95 \text{ V to } 2.7 \text{ V}$	1.6		V
			$V_{CCI} = 2.7 \text{ V to } 3.6 \text{ V}$	2		
			$V_{CCI} = 1.2 \text{ V to } 1.95 \text{ V}$		$V_{CCI} \times 0.35$	
V _{IL}	Low-level input voltage ⁽¹⁾	Data inputs	V_{CCI} = 1.95 V to 2.7 V		0.7	V
			$V_{CCI} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$		0.8	
			V _{CCI} = 1.2 V to 1.95 V	$V_{CCA} \times 0.65$		
V _{IH}	High-level input voltage	DIR and \overline{OE} (referenced to V _{CCA})	$V_{CCI} = 1.95 \text{ V to } 2.7 \text{ V}$	1.6		V
			V _{CCI} = 2.7 V to 3.6 V	2		
	Low-level input voltage		V _{CCI} = 1.2 V to 1.95 V		$V_{CCA} \times 0.35$	
VIL		DIR and \overline{OE} (referenced to V _{CCA})	$V_{CCI} = 1.95 \text{ V to } 2.7 \text{ V}$		0.7	V
			V _{CCI} = 2.7 V to 3.6 V		0.8	
VI	Input voltage	Control Inputs		0	3.6	V
V	Output voltage ⁽²⁾	Active state		0	V _{CCO}	V
Vo		3-state		0	3.6	v
			V _{CCO} = 1.2 V		-3	
			V _{CCO} = 1.4 V to 1.6 V		-6	
I _{OH}	High-level output current		$V_{CCO} = 1.65 \text{ V}$ to 1.95 V		-8	mA
			V_{CCO} = 2.3 V to 2.7 V		-9	
			$V_{CCO} = 3 V \text{ to } 3.6 V$		-12	
			V _{CCO} = 1.2 V		3	
			V _{CCO} = 1.4 V to 1.6 V		6	
I _{OL}	Low-level output current		V _{CCO} = 1.65 V to 1.95 V		8	mA
			$V_{CCO} = 2.3 \text{ V to } 2.7 \text{ V}$		9	
	V _{CCO} = 3 V to 3.6 V				12	
Δt/Δv	Input transition rise or fall rate				5	ns/V
T _A	Operating free-air temperature)		-40	85	°C

(1)

 V_{CCI} is the V_{CC} associated with the input port. V_{CCO} is the V_{CC} associated with the output port. (2)

7.4 Thermal Information

			SN74AVCH8T245				
	THERMAL METRIC ⁽¹⁾	DGV (TVSOP)	PW (TSSOP)	RHL (VQFN)	UNIT		
		24 PINS	24 PINS	24 PINS			
R _{θJA}	Junction-to-ambient thermal resistance ⁽²⁾	95.5	92	35	°C/W		
R _{0JC(top)}	Junction-to-case (top) thermal resistance	27	29.3	39.9	°C/W		
$R_{\theta JB}$	Junction-to-board thermal resistance	48.9	46.7	13.8	°C/W		
Ψ _{JT}	Junction-to-top characterization parameter	0.7	1.5	0.3	°C/W		
Ψ _{JB}	Junction-to-board characterization parameter	48.5	46.2	13.8	°C/W		
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	_	_	1.4	°C/W		

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application (1) report, SPRA953.

The package thermal impedance is calculated in accordance with JESD 51-7. (2)



7.5 Electrical Characteristics

All typical limits apply over $T_A = 25^{\circ}C$, and all maximum and minimum limits apply over $T_A = -40^{\circ}C$ to $85^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP	МАХ	UNIT
		I _{OH} = -100 μA, V _I = V _{IH}	$V_{CCA} = V_{CCB} = 1.2$ V to 3.6 V	/ V _{CCO} – 0.2			
		$I_{OH} = -3 \text{ mA}, \text{ V}_{I} = \text{ V}_{IH}$	$V_{CCA} = V_{CCB} = 1.2 V$		0.95		
	High-level output	$I_{OH} = -6 \text{ mA}, V_{I} = V_{IH}$	$V_{CCA} = V_{CCB} = 1.4 V$	1.05			v
V _{ОН}	voltage ⁽¹⁾	$I_{OH} = -8 \text{ mA}, V_I = V_{IH}$	$V_{CCA} = V_{CCB} = 1.65 V$	1.2			v
		$I_{OH} = -9 \text{ mA}, V_{I} = V_{IH}$	$V_{CCA} = V_{CCB} = 2.3 V$	1.75			
		$I_{OH} = -12 \text{ mA}, \text{ V}_{I} = \text{ V}_{IH}$	$V_{CCA} = V_{CCB} = 3 V$	2.3			
		$I_{OL}=100~\mu A,~V_{I}=V_{IL}$	$V_{CCA} = V_{CCB} = 1.2$ V to 3.6 V	/		0.2	
		$I_{OL} = 3 \text{ mA}, V_I = V_{IL}$	$V_{CCA} = V_{CCB} = 1.2 V$		0.15		
v	Low-level output	$I_{OL} = 6 \text{ mA}, V_{I} = V_{IL}$	$V_{CCA} = V_{CCB} = 1.4 V$			0.35	v
V _{OL}	voltage	$I_{OL} = 8 \text{ mA}, V_I = V_{IL}$	$V_{CCA} = V_{CCB} = 1.65 V$			0.45	v
		$I_{OL} = 9 \text{ mA}, V_{I} = V_{IL}$	$V_{CCA} = V_{CCB} = 2.3 V$			0.55	
		I_{OL} = 12 mA, V_{I} = V_{IL}	$V_{CCA} = V_{CCB} = 3 V$			0.7	
l _l	Control inputs	$V_I = V_{CCA}$ or GND	$V_{CCA} = V_{CCB} = 1.2 \text{ V to } 3.6 \text{ V}$	/	±0.025	±1	μA
		V _I = 0.42 V	$V_{CCA} = V_{CCB} = 1.2 V$		25		
	Bus-hold low	$V_{I} = 0.49 V$	$V_{CCA} = V_{CCB} = 1.4 V$	15			
I _{BHL}	sustaining	V _I = 0.58 V	$V_{CCA} = V_{CCB} = 1.65 V$	25			μA
	current ⁽²⁾	V _I = 0.7 V	$V_{CCA} = V_{CCB} = 2.3 V$	45			
		V _I = 0.8 V	$V_{CCA} = V_{CCB} = 3.3 V$	100			
		V _I = 0.78 V	$V_{CCA} = V_{CCB} = 1.2 V$		-25		
	Bus-hold high	$V_{I} = 0.91 V$	$V_{CCA} = V_{CCB} = 1.4 V$	–15			
I _{BHH}	sustaining	V _I = 1.07 V	$V_{CCA} = V_{CCB} = 1.65 V$	-25			μA
	current ^{(3)⁻}	V _I = 1.6 V	$V_{CCA} = V_{CCB} = 2.3 V$	-45			
		V ₁ = 2 V	$V_{CCA} = V_{CCB} = 3.3 V$	-100			
			$V_{CCA} = V_{CCB} = 1.2 V$		50		
	Bus-hold low		$V_{CCA} = V_{CCB} = 1.6 V$	125			
I _{BHLO}	overdrive	$V_I = 0$ to V_{CC}	$V_{CCA} = V_{CCB} = 1.95 V$	200			μA
	current ⁽⁴⁾		$V_{CCA} = V_{CCB} = 2.7 V$	300			
			$V_{CCA} = V_{CCB} = 3.6 V$	500			
			$V_{CCA} = V_{CCB} = 1.2 V$		-50		
	Bus-hold high		$V_{CCA} = V_{CCB} = 1.6 V$	-125			
I _{BHHO}	overdrive	$V_I = 0$ to V_{CC}	$V_{CCA} = V_{CCB} = 1.95 V$	-200			μA
	current ⁽⁵⁾		$V_{CCA} = V_{CCB} = 2.7 V$	-300			
			$V_{CCA} = V_{CCB} = 3.6 V$	-500			
	Input/output	$V_{I} = 0 V \text{ to } 3.6 V,$	$\begin{array}{c} V_{CCA}=0 \ V, \\ V_{CCB}=0 \ V \ to \ 3.6 \ V \end{array} \hspace{0.5cm} A \ Po \end{array}$	rt	±0.1	±5	
l _{off}	power-off leakge current	$V_{O}= 0 V \text{ to } 3.6 V$	$\begin{array}{c} V_{CCA} = 0 \ V \ \text{to} \ 3.6 \ V, \\ V_{CCB} = 0 \ V \end{array} B \ \text{Po} \end{array}$	rt	±0.1	±5	μA

 V_{CCO} is the V_{CC} associated with the output port. (1)

- The bus-hold circuit can source at least the minimum high sustaining current at VIH min. IBHH should be measured after raising VIN to (3) V_{CC} and then lowering it to V_{IH} min.
- An external driver must source at least IBHLO to switch this node from low to high. (4)
- An external driver must sink at least IBHHO to switch this node from high to low. (5)

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⁽²⁾ The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to $V_{\text{IL}}\xspace$ max.

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Electrical Characteristics (continued)

All typical limits apply over $T_A = 25^{\circ}C$, and all maximum and minimum limits apply over $T_A = -40^{\circ}C$ to $85^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST C	ONDITIONS		MIN	ТҮР	MAX	UNIT
		$V_{O} = V_{CCO} \text{ or } GND,$ $V_{I} = V_{CCI} \text{ or } GND, \overline{OE} = V_{IH}$	$V_{CCA} = V_{CCB} = 3.6 V$	A Port, B Port		±0.5	±5	
I _{OZ}	^{IOZ} current ⁽¹⁾⁽⁶⁾⁽⁷⁾ $V_0 = V_{CC0}$ or GND, $V_1 = V_{CC1}$ or GND, $\overline{OE} = \text{Don't Care}$		$\begin{array}{l} V_{CCA}=0 \ V, \\ V_{CCB}=3.6 \ V \end{array}$	B Port			±5	μA
			$\begin{array}{l} V_{CCA}=3.6 \ V, \\ V_{CCB}=0 \ V \end{array}$	A Port			±5	
			$V_{CCA} = V_{CCB} = 1.2 \text{ V to}$	o 3.6 V			8	
I _{CCA}	Supply current A port ⁽⁶⁾	$V_I = V_{CCI}$ or GND, $I_O = 0$	$V_{CCA} = 0 V, V_{CCB} = 3.0$	6 V			-2	μA
	port		$V_{CCA} = 3.6 V, V_{CCB} = 0$	$V_{CCA} = 3.6 V, V_{CCB} = 0 V$			8	
			$V_{CCA} = V_{CCB} = 1.2 \text{ V to } 3.6 \text{ V}$ = V _{CCI} or GND, I _O = 0 V _{CCA} = 0 V, V _{CCB} = 3.6 V				8	
I _{CCB}	Supply current B port ⁽⁶⁾	$V_I = V_{CCI}$ or GND, $I_O = 0$					8	μA
	port		$V_{CCA} = 3.6 \text{ V}, V_{CCB} = 0 \text{ V}$				-2	
I _{CCA} + I _{CCB}	Combined supply current ⁽⁶⁾	$V_{I} = V_{CCI}$ or GND, $I_{O} = 0$	$V_{CCA} = V_{CCB} = 1.2 \text{ V to}$	o 3.6 V			16	μA
Ci	Input capacitance control pins	V _I = 3.3 V or GND	$V_{CCA} = V_{CCB} = 3.3 V$			3.5	4.5	pF
C _{io}	Input/output capacitance a or b port	V _O = 3.3 V or GND	$V_{CCA} = V_{CCB} = 3.3 \text{ V}$			6	7	pF

 $\begin{array}{ll} \mbox{(6)} & V_{CCI} \mbox{ is the } V_{CC} \mbox{ associated with the input port.} \\ \mbox{(7)} & \mbox{For I/O ports, the parameter } I_{OZ} \mbox{ includes the input leakage current.} \end{array}$



7.6 Switching Characteristics, $V_{CCA} = 1.2 V$

$T_A= 25^{\circ}C$ (see Figure 10)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN TYP	МАХ	UNIT					
				V _{CCB} = 1.2 V	3.1							
	Propagation delay time:			V _{CCB} = 1.5 V	2.6							
t _{PLH} , t _{PHL}	low-to-high-level output and	Α	В	V _{CCB} = 1.8 V	2.5		ns					
PHL	high-to-low level output			V _{CCB} = 2.5 V	3							
				V _{CCB} = 3.3 V	3.5							
				V _{CCB} = 1.2 V	3.1							
	Propagation delay time:			V _{CCB} = 1.5 V	2.7							
t _{PLH} , t _{PHL}	low-to-high-level output and	В	А	V _{CCB} = 1.8 V	2.5		ns					
PHL	PHL high-to-low level output			V _{CCB} = 2.5 V	2.4							
				V _{CCB} = 3.3 V	2.3							
				V _{CCB} = 1.2 V	5.3							
	Enable time:			V _{CCB} = 1.5 V	5.3							
t _{PZH} ,	to high level and	ŌĒ	A	V _{CCB} = 1.8 V	5.3		ns					
t _{PZL}	to low level			V _{CCB} = 2.5 V	5.3							
				V _{CCB} = 3.3 V	5.3							
			В	V _{CCB} = 1.2 V	5.1							
	Enable time:			V _{CCB} = 1.5 V	4		ns					
t _{PZH} ,	to high level and	ŌĒ		V _{CCB} = 1.8 V	3.5							
t _{PZL}	to low level									V _{CCB} = 2.5 V	3.2	
				V _{CCB} = 3.3 V	3.1							
				V _{CCB} = 1.2 V	4.8							
	Disable time:			V _{CCB} = 1.5 V	4.8							
t _{PHZ} ,	from high level and	OE	А	V _{CCB} = 1.8 V	4.8		ns					
t _{PLZ}	from low level			V _{CCB} = 2.5 V	4.8							
				V _{CCB} = 3.3 V	4.8							
				V _{CCB} = 1.2 V	4.7							
	Disable time:			V _{CCB} = 1.5 V	4		ns					
t _{PHZ} ,	from high level and	ŌĒ	В	V _{CCB} = 1.8 V	4.1							
t _{PLZ}	from low level			V _{CCB} = 2.5 V	4.3							
				V _{CCB} = 3.3 V	5.1							

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7.7 Switching Characteristics, V_{CCA} = 1.5 V ± 0.1 V

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	ТҮР	МАХ	UNIT	
				V _{CCB} = 1.2 V		2.7			
	Propagation delay time:			V _{CCB} = 1.5 V	0.5		5.4		
t _{PLH} , t _{PHL}	low-to-high-level output and	А	В	V _{CCB} = 1.8 V	0.5		4.6	ns	
PHL	high-to-low level output			V _{CCB} = 2.5 V	0.5		4.9		
				V _{CCB} = 3.3 V	0.5		6.8		
				V _{CCB} = 1.2 V		2.6			
	Propagation delay time:			V _{CCB} = 1.5 V	0.5		5.4		
t _{PLH} , t _{PHL}	low-to-high-level output and	В	А	V _{CCB} = 1.8 V	0.5		5.1	ns	
PHL	high-to-low level output			V _{CCB} = 2.5 V	0.5		4.7		
			V _{CCB} = 3.3 V	0.5		4.5			
				V _{CCB} = 1.2 V		3.7			
	Enable time:			V _{CCB} = 1.5 V	1.1		8.7		
t _{PZH} , t _{PZL}	to high level and	ŌĒ	А	V _{CCB} = 1.8 V	1.1		8.7	ns	
ΨZL	to low level			V _{CCB} = 2.5 V	1.1		8.7		
				V _{CCB} = 3.3 V	1.1		8.7		
			В	V _{CCB} = 1.2 V		4.8			
	Enable time:			V _{CCB} = 1.5 V	1.1		7.6	ns	
t _{PZH} , t _{PZL}	to high level and	ŌE		V _{CCB} = 1.8 V	1.1		7.1		
PZL	to low level			V _{CCB} = 2.5 V	1.1		5.6		
				V _{CCB} = 3.3 V	1.1		5.2		
				V _{CCB} = 1.2 V		3.1			
	Disable time:			V _{CCB} = 1.5 V	0.5		8.6		
t _{PHZ} , t _{PLZ}	from high level and	OE	А	V _{CCB} = 1.8 V	0.5		8.6	ns	
PLZ	from low level			V _{CCB} = 2.5 V	0.5		8.6		
				V _{CCB} = 3.3 V	0.5		8.6		
				V _{CCB} = 1.2 V		4.1			
	Disable time:			V _{CCB} = 1.5 V	0.5		8.4		
t _{PHZ} , t _{PLZ}	from high level and	ŌĒ	В	V _{CCB} = 1.8 V	0.5		7.6		
۲LZ	from low level			V _{CCB} = 2.5 V	0.5		7.2		
				V _{CCB} = 3.3 V	0.5		7.8		



7.8 Switching Characteristics, V_{CCA} = 1.8 V ± 0.15 V

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	ТҮР	МАХ	UNIT
				V _{CCB} = 1.2 V		2.5		
	Propagation delay time:			V _{CCB} = 1.5 V	0.5		5.1	
t _{PLH} , t _{PHL}	low-to-high-level output and	Α	В	V _{CCB} = 1.8 V	0.5		4.4	ns
PHL	high-to-low level output			V _{CCB} = 2.5 V	0.5		4	
				V _{CCB} = 3.3 V	0.5		3.9	
				V _{CCB} = 1.2 V		2.5		
ı.	Propagation delay time:			V _{CCB} = 1.5 V	0.5		4.6	
t _{PLH} , t _{PHL}	low-to-high-level output and	В	А	V _{CCB} = 1.8 V	0.5		4.4	ns
PHL	high-to-low level output			V _{CCB} = 2.5 V	0.5		3.9	
				V _{CCB} = 3.3 V	0.5		3.7	
				V _{CCB} = 1.2 V		3		
	Enable time:			V _{CCB} = 1.5 V	1		6.8	
t _{PZH} , t _{PZL}	to high level and	ŌĒ	A	V _{CCB} = 1.8 V	1		6.8	ns
PZL	to low level			V _{CCB} = 2.5 V	1		6.8	
				V _{CCB} = 3.3 V	1		6.8	
				V _{CCB} = 1.2 V		4.6		
	Enable time:		В	V _{CCB} = 1.5 V	1.1		8.2	ns
t _{PZH} , t _{PZL}	to high level and	ŌE		V _{CCB} = 1.8 V	1		6.7	
PZL	to low level			V _{CCB} = 2.5 V	0.5		5.1	
				V _{CCB} = 3.3 V	0.5		4.5	
				V _{CCB} = 1.2 V		2.8		
	Disable time:			V _{CCB} = 1.5 V	0.5		7.1	
t _{PHZ} , t _{PLZ}	from high level and	ŌE	А	V _{CCB} = 1.8 V	0.5		7.1	ns
PLZ	from low level			V _{CCB} = 2.5 V	0.5		7.1	
				V _{CCB} = 3.3 V	0.5		7.1	
				V _{CCB} = 1.2 V		3.9		
	Disable time:			V _{CCB} = 1.5 V	0.5		7.8	
t _{PHZ} , t _{PLZ}	from high level and	ŌĒ	В	V _{CCB} = 1.8 V	0.5		6.9	5
۰۳LZ	from low level			V _{CCB} = 2.5 V	0.5		6	
				V _{CCB} = 3.3 V	0.5		5.8	

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7.9 Switching Characteristics, V_{CCA} = 2.5 V ± 0.2 V

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	ТҮР	МАХ	UNIT
				V _{CCB} = 1.2 V		2.4		
	Propagation delay time:			V _{CCB} = 1.5 V	0.5		4.7	
t _{PLH} , t _{PHL}	low-to-high-level output and	А	В	V _{CCB} = 1.8 V	0.5		3.9	ns
PHL	high-to-low level output			V _{CCB} = 2.5 V	0.5		3.1	
				V _{CCB} = 3.3 V	0.5		2.8	
				V _{CCB} = 1.2 V		3		
	Propagation delay time:			V _{CCB} = 1.5 V	0.5		4.9	
t _{PLH} , touu	low-to-high-level output and	В	А	V _{CCB} = 1.8 V	0.5		4	ns
t _{PHL} high-to-low level output			V _{CCB} = 2.5 V	0.5		3.1		
			V _{CCB} = 3.3 V	0.5		2.9		
				V _{CCB} = 1.2 V		2.2		
	Enable time:	ŌĒ		V _{CCB} = 1.5 V	0.5		4.8	ns
to high level and	to high level and		A	V _{CCB} = 1.8 V	0.5		4.8	
t _{PZL}	to low level			V _{CCB} = 2.5 V	0.5		4.8	
				V _{CCB} = 3.3 V	0.5		4.8	
				V _{CCB} = 1.2 V		4.5		
	Enable time:			V _{CCB} = 1.5 V	1.1		7.9	ns
t _{PZH} , t _{PZL}	to high level and	ŌĒ	В	V _{CCB} = 1.8 V	0.5		6.4	
۹ZL	to low level			V _{CCB} = 2.5 V	0.5		4.6	
				V _{CCB} = 3.3 V	0.5		4	
				V _{CCB} = 1.2 V		1.8		
	Disable time:			V _{CCB} = 1.5 V	0.5		5.1	
t _{PHZ} , t _{PHZ} ,	from high level and	ŌĒ	А	V _{CCB} = 1.8 V	0.5		5.1	ns
t _{PLZ}	from low level			V _{CCB} = 2.5 V	0.5		5.1	
				V _{CCB} = 3.3 V	0.5		5.1	
				V _{CCB} = 1.2 V		3.6		
	Disable time:			V _{CCB} = 1.5 V	0.5		7.1	
t _{PHZ} , t _{PLZ} ,	from high level and	ŌĒ	В	V _{CCB} = 1.8 V	0.5		6.3	-
t _{PLZ}	from low level			V _{CCB} = 2.5 V	0.5		5.1	
			V _{CCB} = 3.3 V	0.5		3.9	1	



7.10 Switching Characteristics, V_{CCA} = 3.3 V ± 0.3 V

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	ТҮР	МАХ	UNIT
				V _{CCB} = 1.2 V		2.3		
	Propagation delay time:			V _{CCB} = 1.5 V	0.5		4.5	
t _{PLH} , t _{PHL}	low-to-high-level output and	Α	В	V _{CCB} = 1.8 V	0.5		3.7	ns
PHL	high-to-low level output			V _{CCB} = 2.5 V	0.5		2.9	
				V _{CCB} = 3.3 V	0.5		2.5	
				V _{CCB} = 1.2 V		3.5		
	Propagation delay time:			V _{CCB} = 1.5 V	0.5		6.8	
t _{PLH} , t _{PHL}	low-to-high-level output and	В	А	V _{CCB} = 1.8 V	0.5		3.9	ns
PHL	high-to-low level output			V _{CCB} = 2.5 V	0.5		2.8	
				V _{CCB} = 3.3 V	0.5		2.5	
				V _{CCB} = 1.2 V		2		
	Enable time:			V _{CCB} = 1.5 V	0.5		4	
t _{PZH} , t _{PZL}	to high level and	ŌĒ	A	V _{CCB} = 1.8 V	0.5		4	ns
4PZL	to low level			V _{CCB} = 2.5 V	0.5		4	
				V _{CCB} = 3.3 V	0.5		4	
				V _{CCB} = 1.2 V		4.5		
	Enable time:			V _{CCB} = 1.5 V	1.1		7.8	ns
t _{PZH} , t _{PZL}	to high level and	ŌE	ËВ	V _{CCB} = 1.8 V	0.5		6.2	
*PZL	to low level			V _{CCB} = 2.5 V	0.5		4.5	
				V _{CCB} = 3.3 V	0.5		3.9	
				V _{CCB} = 1.2 V		1.7		
	Disable time:			V _{CCB} = 1.5 V	0.5		4	
t _{PHZ} , t _{PLZ}	from high level and	OE	А	V _{CCB} = 1.8 V	0.5		4	ns
PLZ	from low level			V _{CCB} = 2.5 V	0.5		4	
				V _{CCB} = 3.3 V	0.5		4	
				V _{CCB} = 1.2 V		3.4		
	Disable time:			V _{CCB} = 1.5 V	0.5		6.9	
t _{PHZ} , t _{PLZ}	from high level and from low level	ŌĒ	В	V _{CCB} = 1.8 V	0.5		6	3
'PLZ				V _{CCB} = 2.5 V	0.5		4.8	
				V _{CCB} = 3.3 V	0.5		4.2	

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7.11 Operating Characteristics

T_A= 25°C

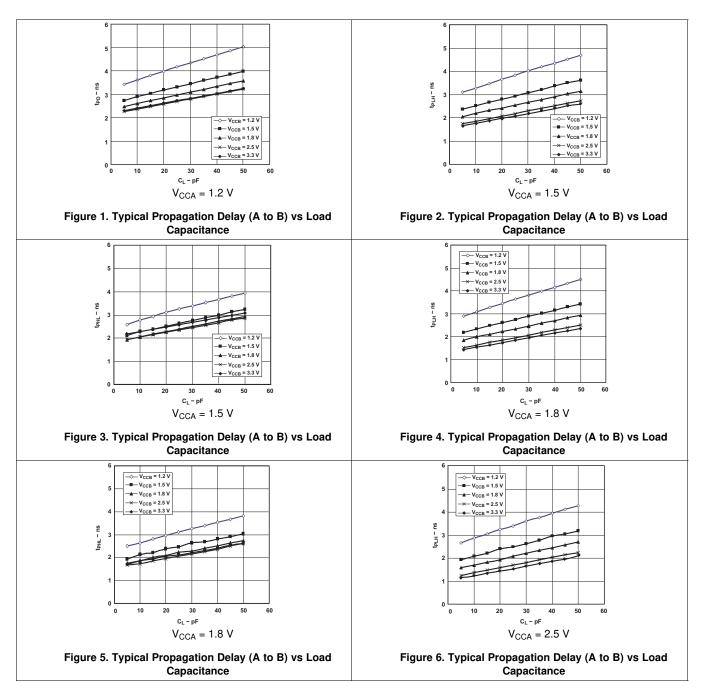
	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TES	T CONDITIONS	ТҮР	UNIT	
					$V_{CCA} = V_{CCB} = 1.2 V$	1		
	Power dissipation capacitance			$C_{1} = 0 pF$,	$V_{CCA} = V_{CCB} = 1.5 V$	1		
	per transceiver ⁽¹⁾	Α	В	f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 V$	1		
	port A - outputs enabled			$t_r = t_f = 1 ns$	$V_{CCA} = V_{CCB} = 2.5 V$	1		
					$V_{CCA} = V_{CCB} = 3.3 V$	1		
				C _L = 0 pF,	$V_{CCA} = V_{CCB} = 1.2 V$	1		
	Power dissipation capacitance				$V_{CCA} = V_{CCB} = 1.5 V$	1		
	per transceiver ⁽¹⁾	Α	В	f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 V$	1		
	port A - outputs disabled			$t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 2.5 V$	1		
C _{pdA}					$V_{CCA} = V_{CCB} = 3.3 V$	1	рF	
					$V_{CCA} = V_{CCB} = 1.2 V$	12	р	
	Power dissipation capacitance			C _L = 0 pF,	$V_{CCA} = V_{CCB} = 1.5 V$	12		
	per transceiver ⁽¹⁾	В	А	f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 V$	12		
	port A - outputs enabled			$t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 2.5 V$	13		
					$V_{CCA} = V_{CCB} = 3.3 V$	14		
				$V_{CCA} = V_{CCB} = 1.2 V$	1			
	Power dissipation capacitance		A	$C_{L} = 0 \text{ pF},$ f = 10 MHz, t _r = t _f = 1 ns	$V_{CCA} = V_{CCB} = 1.5 V$	1		
	per transceiver ⁽¹⁾	В			$V_{CCA} = V_{CCB} = 1.8 V$	1		
	port A - outputs disabled				$V_{CCA} = V_{CCB} = 2.5 V$	1		
					$V_{CCA} = V_{CCB} = 3.3 V$	1		
					$V_{CCA} = V_{CCB} = 1.2 V$	12		
	Power dissipation capacitance	A		$C_1 = 0 pF$,	$V_{CCA} = V_{CCB} = 1.5 V$	12		
	per transceiver ⁽¹⁾		В	f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 V$	12		
	port B - outputs enabled			$t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 2.5 V$	13		
					$V_{CCA} = V_{CCB} = 3.3 V$	14		
					$V_{CCA} = V_{CCB} = 1.2 V$	1		
	Power dissipation capacitance			$C_{I} = 0 \text{ pF},$	$V_{CCA} = V_{CCB} = 1.5 V$	1		
	per transceiver ⁽¹⁾	Α	В	f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 V$	1	l .	
	port B - outputs disabled			$t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 2.5 V$	1		
~					$V_{CCA} = V_{CCB} = 3.3 V$	1		
C _{pdB}					$V_{CCA} = V_{CCB} = 1.2 V$	1	pF	
	Power dissipation capacitance			C _L = 0 pF,	$V_{CCA} = V_{CCB} = 1.5 V$	1		
	per transceiver ⁽¹⁾	В	А	f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 V$	1		
	port B - outputs enabled			$t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 2.5 V$	1	ĺ	
					$V_{CCA} = V_{CCB} = 3.3 \text{ V}$	1		
					$V_{CCA} = V_{CCB} = 1.2 V$	1		
	Power dissipation capacitance			C _L = 0 pF,	$V_{CCA} = V_{CCB} = 1.5 V$	1	-	
	per transceiver ⁽¹⁾	В	А	$G_{L} = 0 \text{ pr},$ f = 10 MHz,	$V_{CCA} = V_{CCB} = 1.8 V$	1		
	port B - outputs disabled	В		$t_r = t_f = 1 \text{ ns}$	$V_{CCA} = V_{CCB} = 2.5 V$	1		
					$V_{CCA} = V_{CCB} = 3.3 \text{ V}$	1	1	

(1) See to TI application report, CMOS Power Consumption and Cpd Calculation (SCAA035).



7.12 Typical Characteristics

 $T_A = 25^{\circ}C$

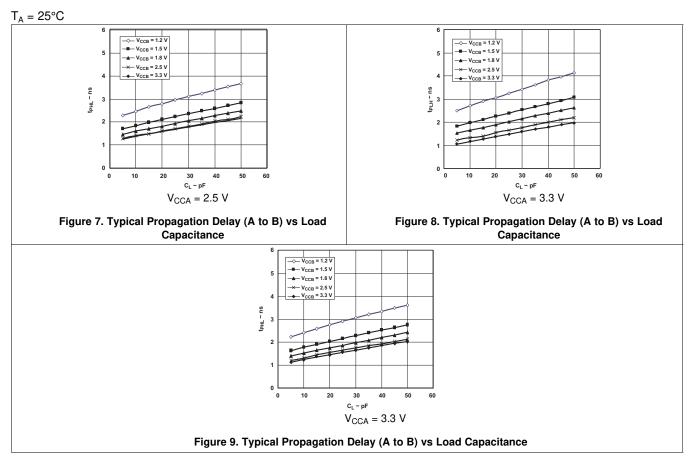


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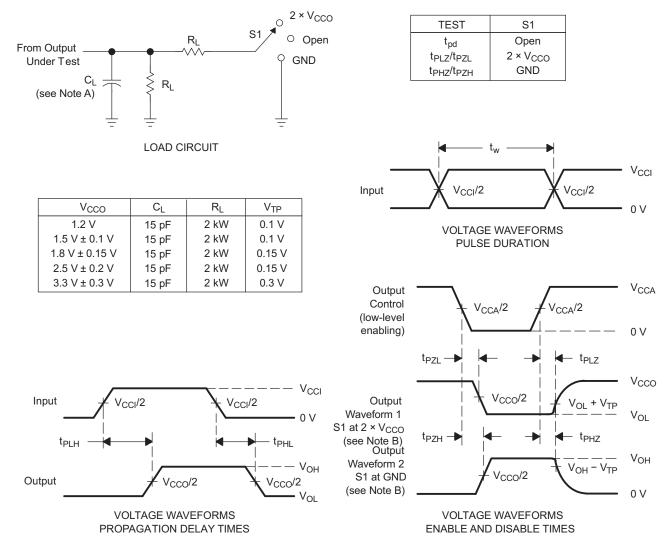
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Typical Characteristics (continued)





8 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR 10 MHz, $Z_0 = 50$ W, $dv/dt \ge 1$ V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.

Figure 10. Load Circuit and Voltage Waveforms

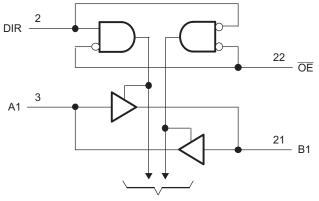
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9 Detailed Description

9.1 Overview

The SN74AVCH8T245 is an 8-bit, dual supply noninverting bidirectional voltage level translator. Pins A1 through A4, and the control pins (DIR and \overline{OE}) are referenced to V_{CCA}, while pins B1 through B4 are referenced to V_{CCB}. Both the A port and B port can accept I/O voltages ranging from 1.2 V to 3.6 V. With \overline{OE} set to low, a high on DIR allows data transmission from Port A to Port B, and a low on DIR allows data transmission from Port B to Port A. When \overline{OE} is set to high, both Port A and Port B outputs are in the high-impedance state. See AVC Logic Family Technology and Application (SCEA006).

9.2 Functional Block Diagram



To Seven Other Channels

Figure 11. Logic Diagram (Positive Logic)

9.3 Feature Description

9.3.1 Fully Configurable Dual-Rail Design

Both V_{CCA} and V_{CCB} can be supplied at any voltage from 1.2 V to 3.6 V, making the device suitable for translating between any of the low voltage nodes: 1.2 V, 1.8 V, 2.5 V, and 3.3 V.

V			۷c	CA			UNIT
V _{CCB}	0 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	UNIT
0 V	0	<0.5	<0.5	<0.5	<0.5	<0.5	
1.2 V	<0.5	<1	<1	<1	<1	1	
1.5 V	<0.5	<1	<1	<1	<1	1	
1.8 V	<0.5	<1	<1	<1	<1	<1	μA
2.5 V	<0.5	1	<1	<1	<1	<1	
3.3 V	<0.5	1	<1	<1	<1	<1	

Table 1. Typical Total Static Power Consumption (I_{CCA} + I_{CCB})

9.3.2 Supports High-Speed Translation

SN74AVCH8T245 can support high data rate applications, which can be calculated from the maximum propagation delay. This is also dependent on output load. The translated signal data rate can be up to 320 Mbps when both V_{CCA} and V_{CCB} are at least 1.8 V.

9.3.3 Partial-Power-Down Mode Operation

l_{off} circuitry disables the outputs, preventing damaging current backflow through the SN74AVCH8T245 when it is powered down. This can occur in applications where subsections of a system are powered down (partial-powerdown) to reduce power consumption.



9.3.4 Bus-Hold Circuitry

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Active bus-hold circuitry holds unused or undriven data inputs at a valid logic state, which helps with board space savings and reduced component costs. Use of pull-up or pull-down resistors with the bus-hold circuitry is not recommended. See *Bus-Hold Circuit* (SCLA015).

9.3.5 V_{CC} Isolation Feature

The V_{CC} isolation feature ensures that if either V_{CCA} or V_{CCB} are at GND (or < 0.4 V), both ports will be in a high-impedance state (I_{OZ} shown in *Electrical Characteristics*). This prevents false logic levels from being presented to either bus.

9.4 Device Functional Modes

Table 2 lists the functional modes of the SN74AVCH8T245.

CONTROL	CONTROL INPUTS ⁽¹⁾		CIRCUITS	OPERATION
OE	DIR	A PORT	B PORT	OPERATION
L	L	Enabled	Hi-Z	B data to A bus
L	н	Hi-Z	Enabled	A data to B bus
Н	Х	Hi-Z	Hi-Z	Isolation

Table 2. Function Table (Each 8-Bit Section)

(1) Input circuits of the data I/Os are always active.



10 Application and Implementation

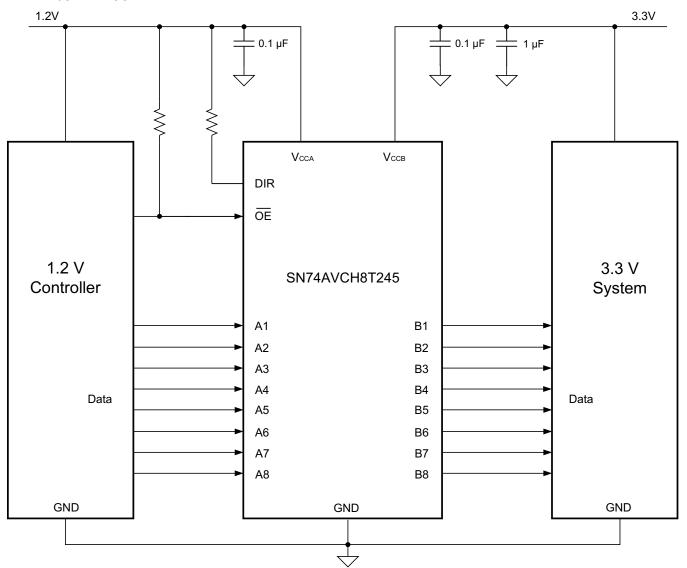
NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74AVCH8T245 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The SN74AVCH8T245 device is ideal for data transmission which direction is different with each channel. The maximum data rate can be up to 320 Mbps when device voltage power supply is more than 1.8 V.

10.2 Typical Application







Typical Application (continued)

10.2.1 Design Requirements

For this design example, use the parameters listed in Table 3.

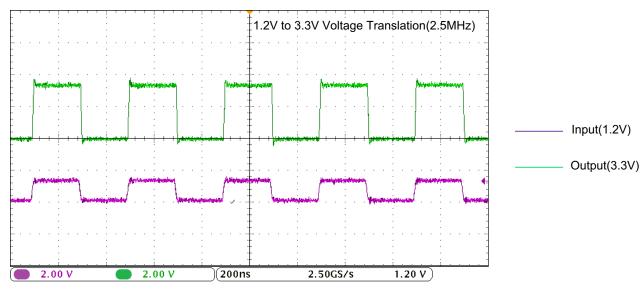
DESIGN PARAMETERS	EXAMPLE VALUE					
Input voltage	1.2 V to 3.6 V					
Output voltage	1.2 V to 3.6 V					

Table 3. Design Parameters

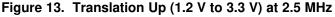
10.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the device that is driving the SN74AVCH8T245 device to determine the input voltage range. For a valid logic high the value must exceed the V_{IH} of the input port. For a valid logic low the value must be less than the V_{IL} of the input port.
- Output voltage range
 - Use the supply voltage of the device that the SN74AVCH8T245 device is driving to determine the output voltage range.



10.2.3 Application Curves



11 Power Supply Recommendations

The output-enable (\overline{OE}) input circuit is designed so that it is referenced to V_{CCA} and when the \overline{OE} input is high, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the \overline{OE} input pin must be tied to V_{CCA} through a pullup resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pullup resistor to V_{CCA} is determined by the current-sinking capability of the driver.

V_{CCA} or V_{CCB} can be powered up first. If the SN74LVCH8T245 is powered up in a permanently enabled state (for example OE is always kept low), pullup resistors are recommended at the input. This ensures proper, glitch-free, power-up. See *Designing with SN4LVCXT245 and SN74LVCHXT245 Family of Direction Controlled Voltage Translators/Level-Shifters* (SLVA746). In addition, the OE pin may be shorted to GND if the application does not require use of the high-impedance state at any time.

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SN74AVCH8T245 SCES565H – APRIL 2004 – REVISED MARCH 2016



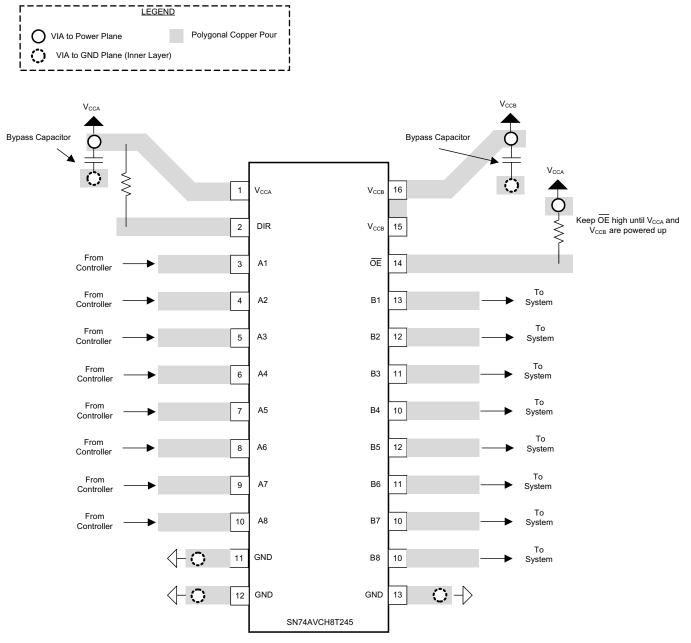
12 Layout

12.1 Layout Guidelines

To ensure reliability of the device, TI recommends following the common printed-circuit board layout guidelines.

- Bypass capacitors should be used on power supplies.
- · Short trace lengths should be used to avoid excessive loading.
- Placing pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals depending on the system requirements.

12.2 Layout Example







13 Device and Documentation Support

13.1 Documentation Support

13.1.1 Related Documentation

For related documentation, see the following:

- Designing with SN74LVCXT245 and SN74LVCHXT245 Family of Direction Controlled Voltage Translators/Level-Shifters, SLVA746
- Bus-Hold Circuit, SCLA015
- AVC Logic Family Technology and Applications, SCEA006
- CMOS Power Consumption and Cpd Calculation, SCAA035

13.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

13.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	Package		Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	6)	(3)		(4/5)	
74AVCH8T245PWRG4	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
74AVCH8T245RHLRG4	ACTIVE	VQFN	RHL	24	1000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WP245	Samples
SN74AVCH8T245DGVR	ACTIVE	TVSOP	DGV	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245PW	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245PWG4	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245PWR	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WP245	Samples
SN74AVCH8T245RHLR	ACTIVE	VQFN	RHL	24	1000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WP245	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

10-Dec-2020

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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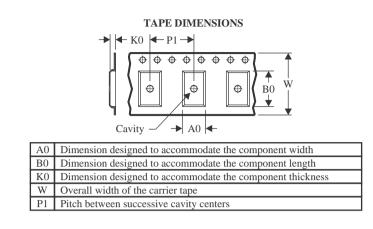


Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

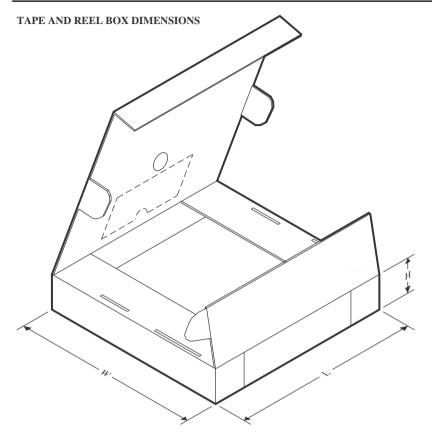


*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVCH8T245DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AVCH8T245PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74AVCH8T245RHLR	VQFN	RHL	24	1000	180.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVCH8T245DGVR	TVSOP	DGV	24	2000	356.0	356.0	35.0
SN74AVCH8T245PWR	TSSOP	PW	24	2000	356.0	356.0	35.0
SN74AVCH8T245RHLR	VQFN	RHL	24	1000	210.0	185.0	35.0

TEXAS INSTRUMENTS

www.ti.com

3-Jun-2022

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74AVCH8T245PW	PW	TSSOP	24	60	530	10.2	3600	3.5
SN74AVCH8T245PWG4	PW	TSSOP	24	60	530	10.2	3600	3.5

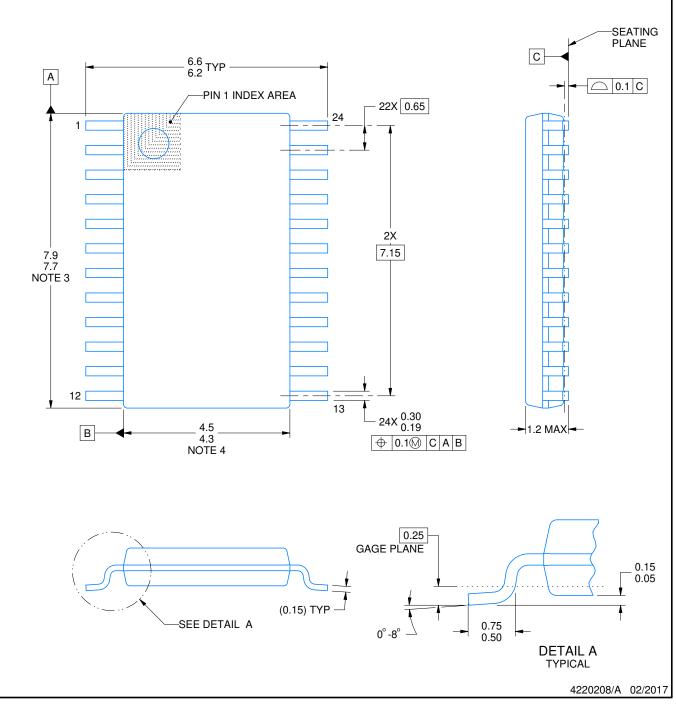
PW0024A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.

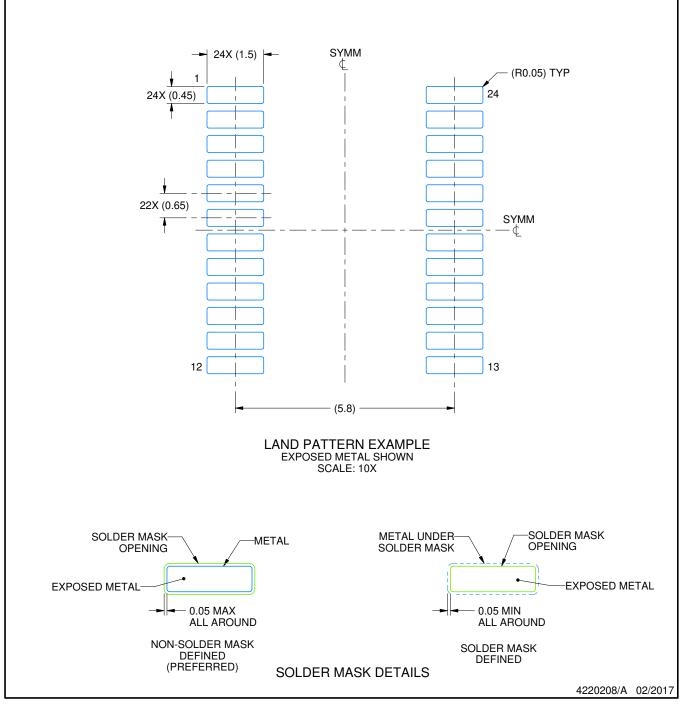


PW0024A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

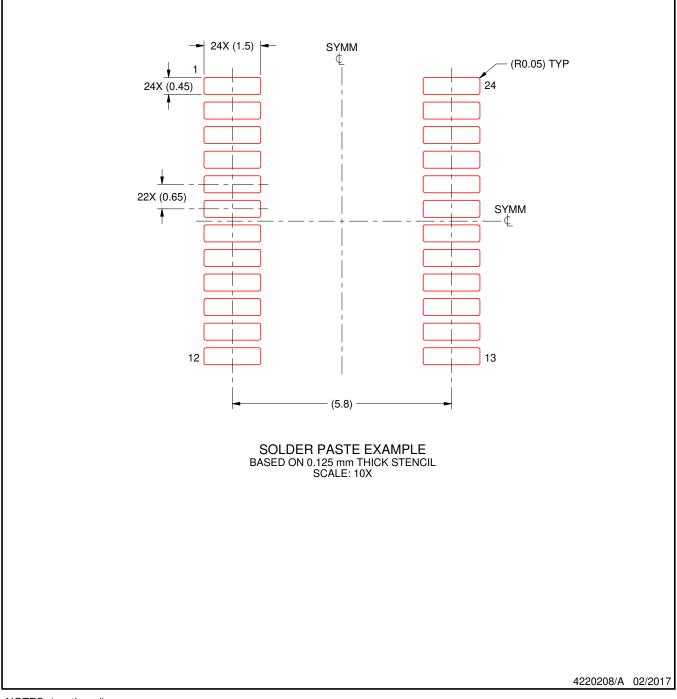


PW0024A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

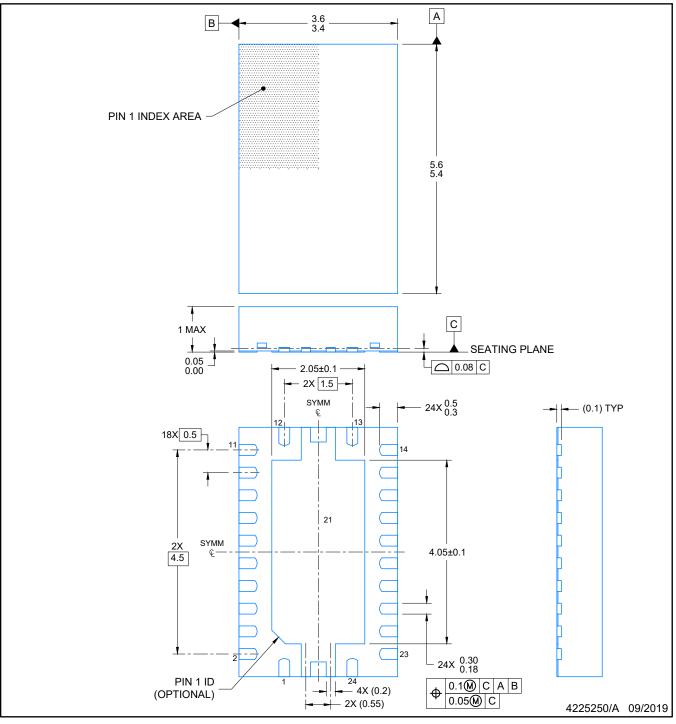


RHL0024A

PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

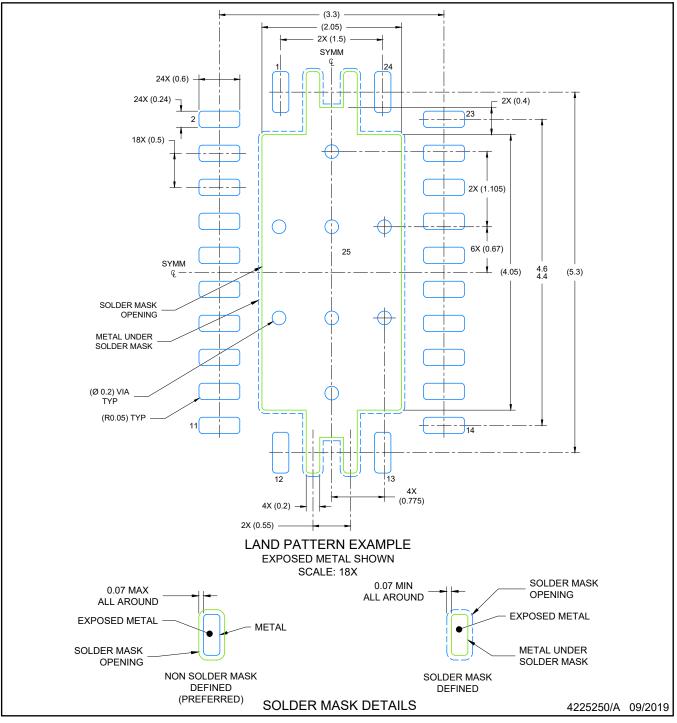


RHL0024A

EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

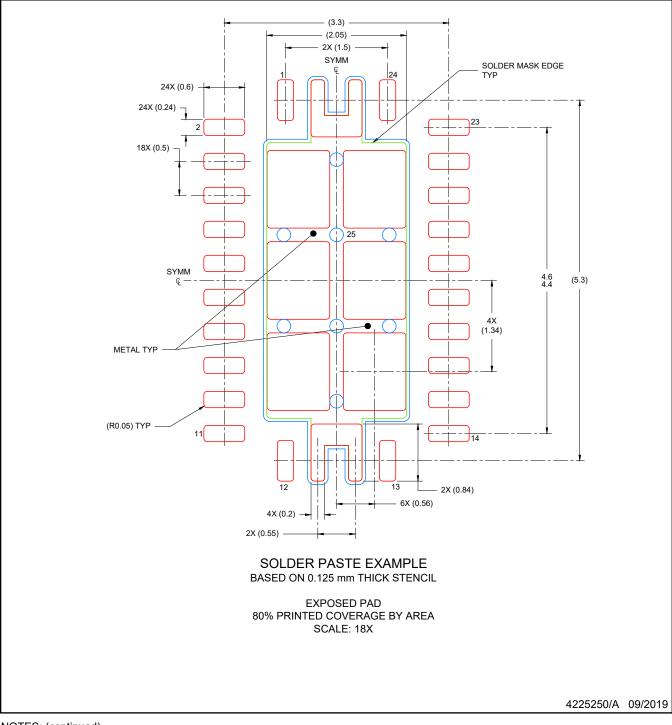


RHL0024A

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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